NSN 5961-00-203-0351 Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
Overall Length:
Between 0.325 inches and 0.355 inches
Overall Height:
0.190 inches
Overall Width:
0.420 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 breakover voltage, dc
Current Rating Per Characteristic:
10.00 amperes source cutoff current preset
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
- <del>-</del>
Demilitarization:
No
Fiig:
A110a0